

TOSHIBA CMOS Linear Integrated Circuit Silicon Monolithic

TCR3DMxxA series

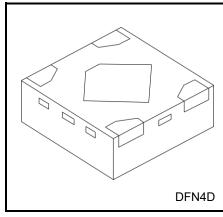
300 mA CMOS Low Drop-Out Regulator with inrush current protection circuit

1. Description

The TCR3DMxxA series are CMOS general-purpose single-output voltage regulators with an on/off control input, featuring low dropout voltage, low output noise voltage, fast load transient response and low inrush current.

These voltage regulators are available in fixed output voltages between 1.0 V and 4.5 V and capable of driving up to 300 mA. They feature Overcurrent protection, Thermal shutdown, Inrush current protection circuit and Auto-discharge.

The TCR3DMxxA series is offered in the ultra small plastic mold package DFN4D (1.0 mm x 1.0 mm; t 0.37 mm (typ.)) and has a low dropout voltage of 216 mV (2.5 V output, IOUT = 300 mA) with low output noise voltage of 38 $\mu Vrms$ (2.5 V output). As small ceramic input and output capacitors 1.0 μF can be used with the TCR3DMxxA series, these devices are ideal for portable applications that require high-density board assembly such as cellular phones.



Weight: 1.1 mg (typ.)

2. Applications

Power IC developed for portable applications

3. Features

- Ultra small package DFN4D (1.0 mm x 1.0 mm; t 0.37 mm (typ.))
- Wide range output voltage line up (Vout = 1.0 to 4.5 V)
- Low dropout voltage

 V_{DO} = 175 mV (typ.) at 3.3 V output, I_{OUT} = 300 mA

 V_{DO} = 216 mV (typ.) at 2.5 V output, I_{OUT} = 300 mA

 $V_{DO} = 297 \text{ mV (typ.)}$ at 1.8 V output, $I_{OUT} = 300 \text{ mA}$

- Low output noise voltage (VNO = $38 \mu V_{rms}$ (typ.) at $10Hz \le f \le 100kHz$)
- High ripple rejection ratio (72 dB (typ.) at 2.5 V output, I_{OUT} = 10 mA, f = 1 kHz)
- Fast load transient response (±80 mV (typ.) at 2.5 V output, I_{OUT} = 1 mA ⇔ 300 mA)
- Overcurrent protection
- Thermal shutdown
- Inrush current protection circuit
- Auto-discharge
- Pull down connection between CONTROL and GND
- Ceramic capacitors can be used (C_{IN} = 1.0 μF, C_{OUT} = 1.0 μF)

Start of commercial production 2023-11



4. Absolute Maximum Ratings (Note) (Ta = 25 °C)

Characteristics	Symbol	Rating	Unit
Input voltage	V _{IN}	-0.3 to 6.0	V
Control voltage	VcT	-0.3 to 6.0	V
Output voltage	Vout	-0.3 to V _{IN} + 0.3 ≤ 6.0	V
Power dissipation	PD	420 (Note1)	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	−55 to 150	°C

Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

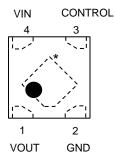
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Rating at mounting on a board

Glass epoxy(FR4) board dimension: 40 mm x 40 mm x 1.6mm, both sides of board. Metal pattern ratio: a surface approximately 50%, the reverse side approximately 50 %

Through hole hall: diameter 0.5 mm x 24 pcs

5. Pin Assignment (Top view)



^{*}Center electrode should be connected to GND or Open

6. Operating Ranges

Characteristics	Symbol		Rating		Unit
Input voltage	VIN	1.5 to 5.5 (Note 2)			V
Control voltage	Vст		0 to 5.5		V
Output voltage	Vout		1.0 to 4.5		V
Output current	lout	DC	300		mA
Operation Temperature	Topr	-40 to 85			°C
Output Capacitance	Cout	≥ 1.0			μF
Input Capacitance	CIN	≥ 1.0			μF

Note 2: Please refer to Dropout Voltage and use it within Absolute Maximum Ratings Junction temperature and Operation Temperature Ranges.



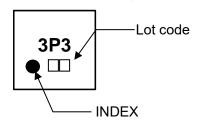
7. List of Products Number, Output voltage and Marking

Product No.	Output voltage (V)	Marking	Product No.	Output voltage (V)	Marking
TCR3DM10A	1.0	1P0	TCR3DM26A*	2.6	2P6
TCR3DM105A	1.05	1PA	TCR3DM27A*	2.7	2P7
TCR3DM11A	1.1	1P1	TCR3DM28A	2.8	2P8
TCR3DM115A*	1.15	1PB	TCR3DM285A*	2.85	2PD
TCR3DM12A	1.2	1P2	TCR3DM29A*	2.9	2P9
TCR3DM13A*	1.3	1P3	TCR3DM2925A*	2.925	2PH
TCR3DM135A*	1.35	1PD	TCR3DM30A*	3.0	3P0
TCR3DM14A*	1.4	1P4	TCR3DM31A*	3.1	3P1
TCR3DM15A	1.5	1P5	TCR3DM32A*	3.2	3P2
TCR3DM16A*	1.6	1P6	TCR3DM33A	3.3	3P3
TCR3DM175A*	1.75	1PE	TCR3DM35A*	3.5	3P5
TCR3DM18A	1.8	1P8	TCR3DM36A*	3.6	3P6
TCR3DM1825A*	1.825	1PF	TCR3DM41A*	4.1	4P1
TCR3DM185A*	1.85	1PG	TCR3DM42A*	4.2	4P2
TCR3DM19A*	1.9	1P9	TCR3DM45A	4.5	4P5
TCR3DM25A	2.5	2P5	_	_	_

^{*} Please contact your local Toshiba representative if you are interested in products with * sign.

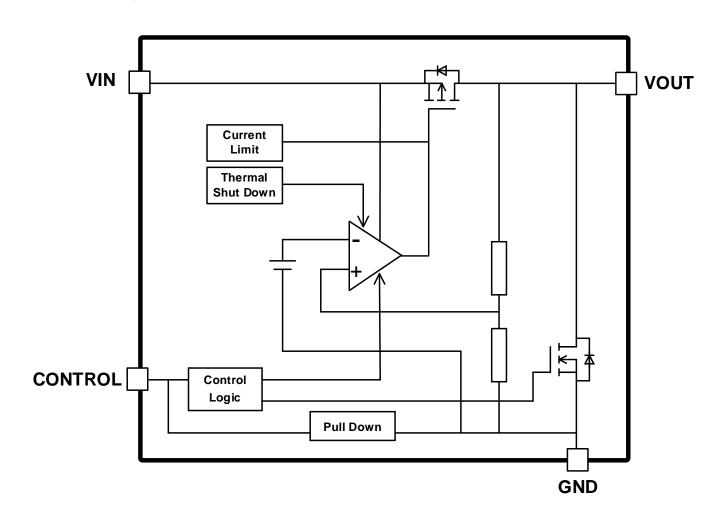
Top Marking (Top view)

Example: TCR3DM33A (3.3 V output)





8. Block Diagram





9. Electrical Characteristics

(Unless otherwise specified, $V_{IN} = V_{OUT} + 1.0 \text{ V}$, $C_{IN} = 1.0 \mu\text{F}$, $C_{OUT} = 1.0 \mu\text{F}$)

Characteristics Symbol		Test Condition		T _j = 25 °C			T _j = -40 to 85 °C (Note 8)		Unit	
				Min	Тур.	Max	Min	Max		
		IOUT = 50 mA	Vout < 1.8 V	-18	_	+18	_	_	mV	
Output voltage accuracy	Vout	V _{IN} = V _{OUT} + 1.0 V (Note 3)	1.8V ≤ V _{OUT}	-1.0	_	+1.0	_	_	%	
Line regulation	Reg·line	$V_{OUT} + 0.5 V \le V_{IN} \le 5.$ $I_{OUT} = 1 \text{ mA}$	5 V	_	1	_	_	_	mV	
Load regulation	Reg·load	1 mA ≤ I _{OUT} ≤ 300 mA		_	18	_	_	52	mV	
Quiescent current	I _{B(ON)}	I _{OUT} = 0 mA V _{IN} = 5.5 V (Note 5)	V _{OUT} = 4.5 V	_	86	_	_	159	μA	
Stand-by current	IB (OFF)	VCT = 0 V, VIN = 5.5 V	(Note 5)	_	0.1	_	_	1	μA	
Control pull down current	Іст	_		-	0.1	_	_	0.2	μA	
	V _{DO}		V _{OUT} = 1.8 V	_	297	335	_	389	mV	
Drop-out voltage (Note 9)		I _{OUT} = 300 mA	V _{OUT} = 2.5 V	_	216	262	_	296	mV	
Drop-out voltage (Note 9)			Vout = 3.3 V	-	175	206	_	242	mV	
			V _{OUT} = 4.5 V		148	179	_	231	mV	
Output noise voltage	V _{NO}	I _{OUT} = 10 mA 10 Hz ≤ f ≤ 100 kHz, Ta = 25 °C (Note 4)		_	38	_	_	_	μV _{rms}	
		f = 100 Hz	1	75	_	_	_			
		$V_{IN} = 3.5 \text{ V}$ $V_{OUT} = 2.5 \text{ V}$ $I_{OUT} = 10 \text{ mA},$ $V_{IN} \text{ Ripple} = 500 \text{ mVp-p},$ $Ta = 25 ^{\circ}\text{C} \text{ (Note 4)}$	f = 1 kHz	-	72	_	_	_	dB	
Ripple rejection ratio	R.R.		f = 10 kHz	-	54	_	_	_		
			f = 100 kHz	_	48	_	_	_		
		14 - 25 5 (11515 1)	f = 1 MHz	-	55	_	_	_		
Landing all and an area	4)./	IOUT = 1 mA → 300 mA	(Note 4) (Note 6)		-80	_	_	_	1 ,,	
Load transient response	Se $\triangle V_{OUT} = 300 \text{ mA} \rightarrow 1 \text{ m/s}$		(Note 4) (Note 6)	-	+80	_	_	_	mV	
Output current limit	I _{CL}	Vout = Vout(NOM)*90 % (Note 7)		-	_	_	320	650	mA	
The arms of a boundaries of the soul of	TSDH	T _J rising			160	_	_	_	°C	
Thermal shutdown threshold	TSDL	T _J falling			130	_	_	_	°C	
Control voltage (HIGH)	Vстн	Control pin input voltage "HIGH"			_	_	0.8	5.5	V	
Control voltage (LOW)	V _{CTL}	Control pin input voltage "LOW"			_	_	0	0.4	V	
Discharge on resistance	RsD	(Note 4)		_	45	_	_	_	Ω	

Note 3: stable state with fixed I_{OUT} condition

Note 4: Vout = 2.5 V

Note 5: except Control pull down current (I_{CT})

Note 6: $t_r = t_f = 1.0 \mu s$ (Defined when 10 % to 90 % is 0.8 μs)

Note 7: Pulse measurement

Note 8: This parameter is warranted by design.

Note 9: V_{DO} = V_{IN1} - (V_{OUT1} x 0.97)

 V_{OUT1} is the output voltage when $V_{IN} = V_{OUT} + 1.0 \text{ V}$.

V_{IN1} is the input voltage at which the output voltage becomes 97 % of V_{OUT1} after gradually decreasing the input voltage.



10. Drop-out voltage table

(IOUT = 300 mA, CIN = 1.0 μ F, COUT = 1.0 μ F)

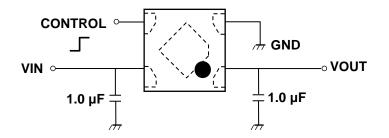
Output voltages	Symbol	T _j = 25 °C			T _j = -40 (Not	Unit	
		Min	Тур.	Max	Min	Max	
1.0 V, 1.05 V		_	642	738	_	790	
1.1 V, 1.15 V		_	566	666	_	716	
1.2 V		_	500	592	_	644	
1.3 V		_	456	535	_	590	
1.35V, 1.4 V		_	434	506	_	563	
1.5 V ≤ V _{OUT} < 1.8 V		_	367	419	_	481	1 ,,
1.8 V ≤ V _{OUT} < 1.9 V	VIN-VOUT	_	297	335	_	389	mV
1.9 V ≤ V _{OUT} < 2.5 V		_	277	309	_	365	
2.5 V ≤ V _{OUT} < 2.8 V		_	216	262	_	296	
2.8 V ≤ V _{OUT} < 3.2 V		_	196	233	_	268	
3.2 V ≤ V _{OUT} < 3.6 V		_	179	211	_	247	
3.6 V ≤ V _{OUT} ≤ 4.5 V		_	168	199	_	240	

Note 10: This parameter is guaranteed by design.



11. Application Note

11.1. Recommended Application Circuit



CONTROL voltage	Output voltage
HIGH	ON
LOW	OFF
OPEN	OFF

The figure above shows the recommended configuration for using a Low-Dropout regulator. Insert a capacitor at Vout and Vin pins for stable input/output operation. (Ceramic capacitors can be used).

11.2. Power Dissipation

Board-mounted power dissipation ratings for TCR3DMxxA series are available in the Absolute Maximum Ratings table. Power dissipation is measured on the board condition shown below.

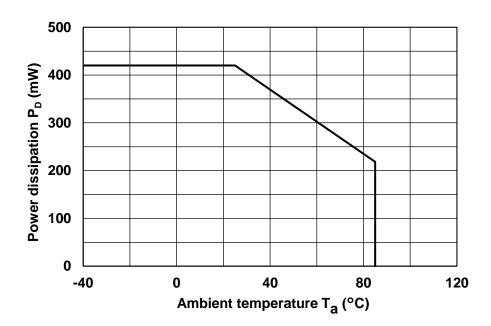
[The Board Condition]

Board material: Glass epoxy(FR4)

Board dimension: 40 mm x 40 mm (both sides of board), t = 1.6 mm

Metal pattern ratio: a surface approximately 50%, the reverse side approximately 50 %

Through hole: diameter 0.5 mm x 24 pcs





11.3. Attention in Use

Output Capacitors

Ceramic capacitors can be used for these devices. However, because of the type of the capacitors, there might be unexpected thermal features. Please consider application condition for selecting capacitors. And Toshiba recommend ceramic capacitor.

Mounting

The long distance between IC and output capacitor might affect phase assurance by impedance in wire and inductor. For stable power supply, output capacitor need to mount near IC as much as possible. Also VIN and GND pattern need to be large and make the wire impedance small as possible.

Permissible Loss

Please have enough design patterns for expected maximum permissible loss. And under consideration of surrounding temperature, input voltage, and output current etc., we recommend proper dissipation ratings for maximum permissible loss; in general maximum dissipation rating is 70 to 80 %.

Over current Protection and Thermal shut down function

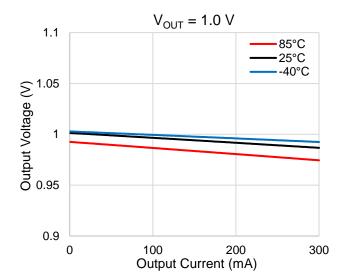
Over current protection and Thermal shut down function are designed in these products, but these are not designed to constantly ensure the suppression of the device within operation limits. Depending on the condition during actual usage, it could affect the electrical characteristic specification and reliability. Also note that if output pins and GND pins are not completely shorted out, these products might be break down. When using these products, please read through and understand the concept of dissipation for absolute maximum ratings from the above mention or our 'Semiconductor Reliability Handbook'. Then use these products under absolute maximum ratings in any condition. Furthermore, Toshiba recommend inserting failsafe system into the design.

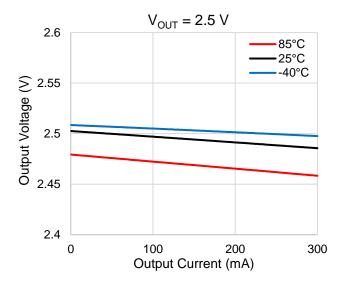


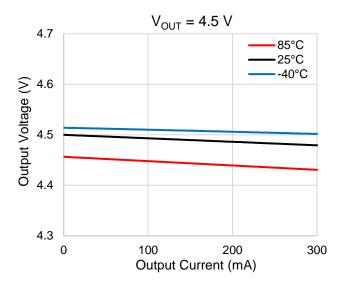
12. Representation Typical Characteristics (Note)

12.1. Output Voltage vs. Output Current

 $(V_{IN} = V_{OUT} + 1.0 V)$

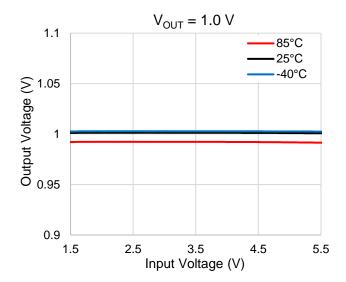


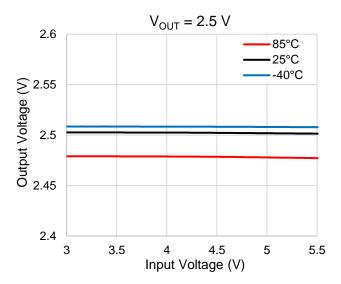


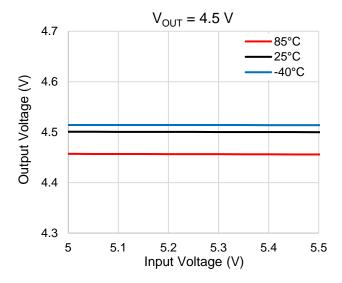




12.2. Output Voltage vs. Input Voltage (lout = 1 mA)

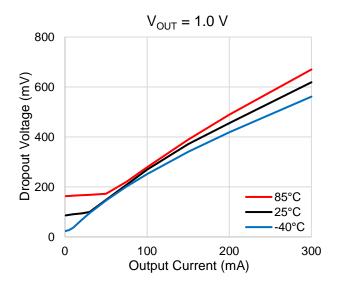


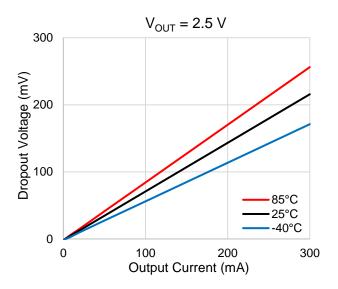


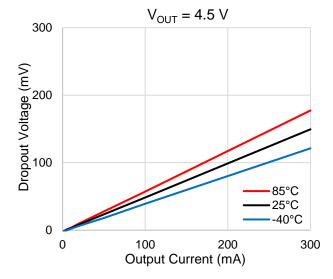




12.3. Dropout Voltage vs. Output Current

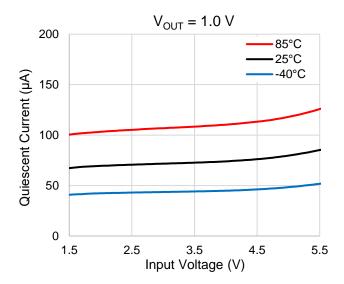


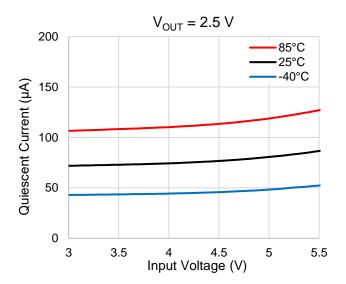


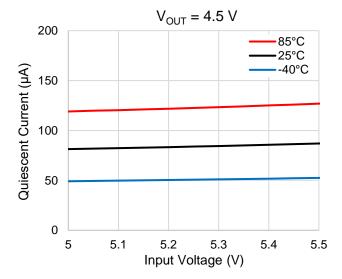




12.4. Quiescent Current vs. Input Voltage (I_{OUT} = 0 mA)



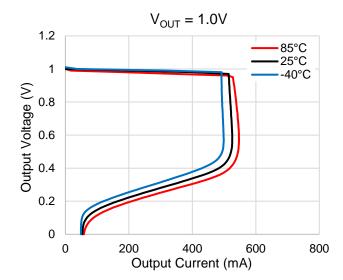


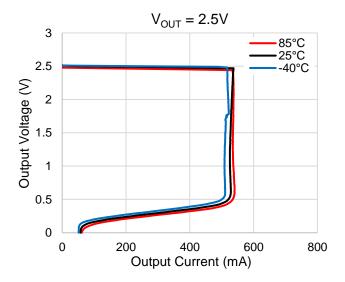


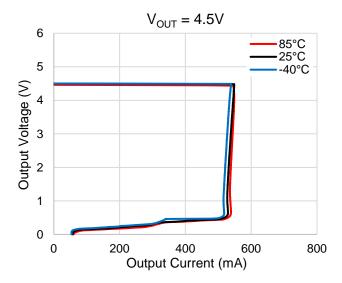


12.5. Output Current Limit

 $(V_{IN} = V_{OUT} + 1.0 V)$



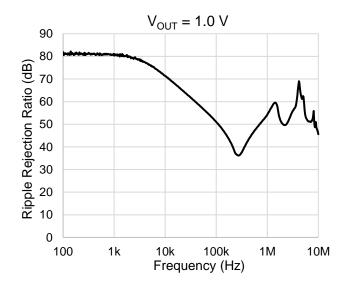


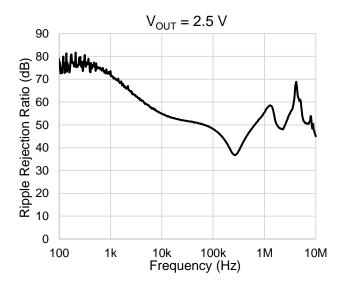


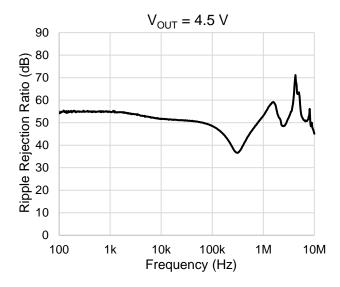


12.6. Ripple rejection Ratio vs. Frequency

(CIN = none, COUT = 1.0 μ F, VIN = VOUT + 1.0 V, VIN Ripple = 500 mV_{p-p}, louT = 10 mA, Ta = 25°C)



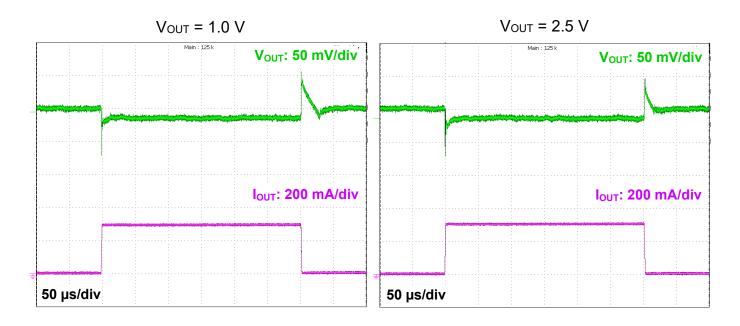


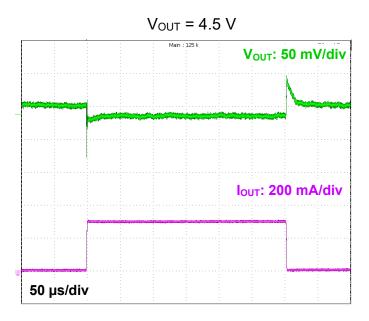




12.7. Load Transient Response

(CIN = 1.0 μ F, COUT = 1.0 μ F, VIN = VOUT + 1.0 V, IOUT = 1 mA \Leftrightarrow 300 mA, tr = 1.0 μ S, tf = 1.0 μ S, Ta = 25°C)







12.8. ton / toff Response

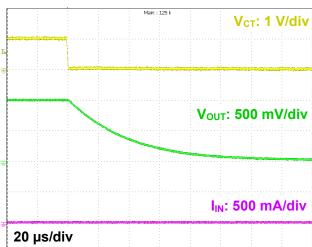
(Cin = 1.0 μ F, Cout = 1.0 μ F, Vin = Vout + 1.0 V, Vct = 0 V \Leftrightarrow 1.0 V, Ta = 25°C)

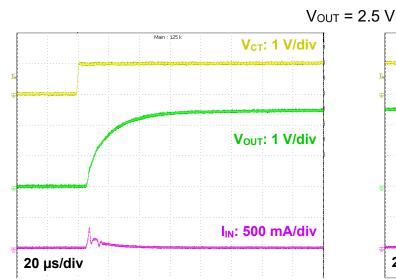
I_{IN}: 500 mA/div

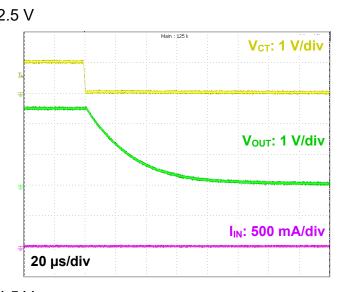
● I_{OUT} = 0 mA

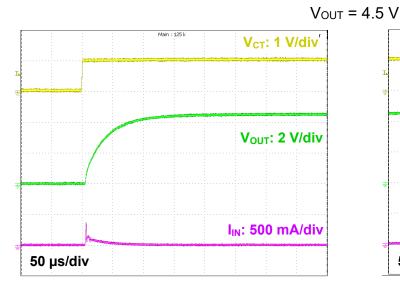
20 µs/div

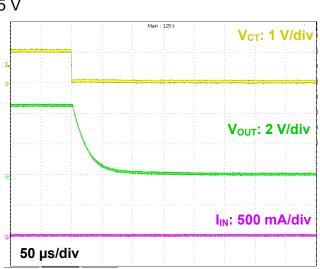




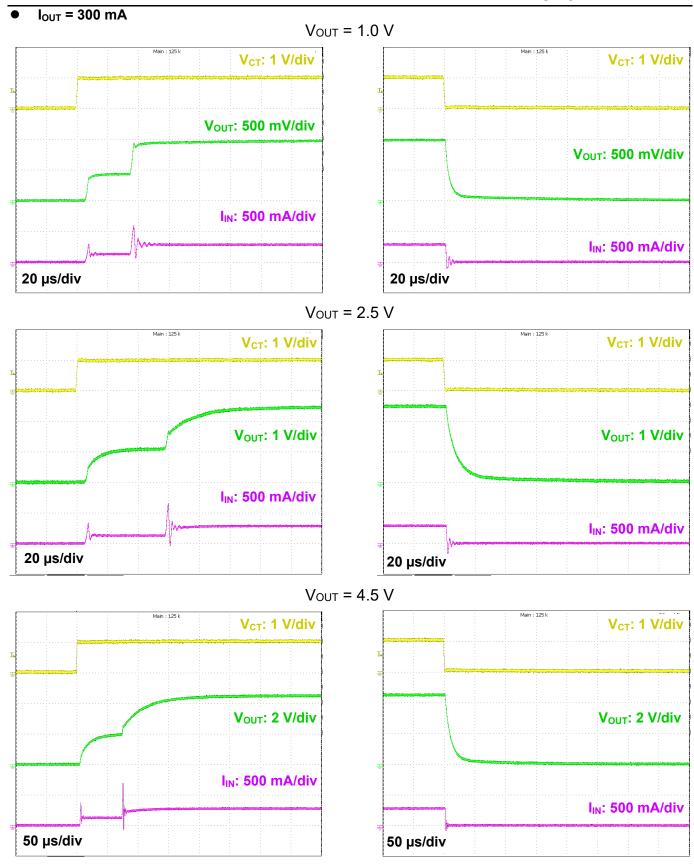










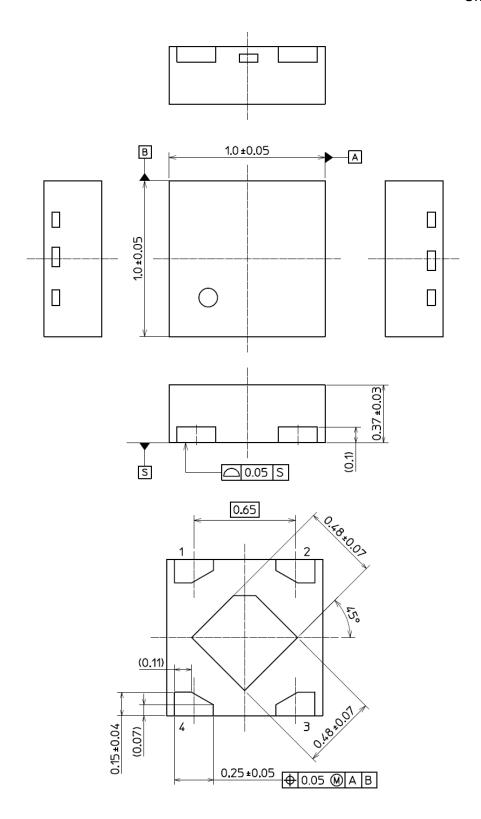




13. Package Information

DFN4D

Unit: mm

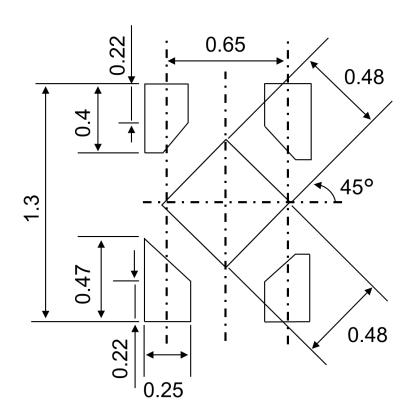


Weight: 1.1 mg (typ.)



14. Land Pattern Dimensions (for reference only)

Unit: mm





RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY
 HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN
 LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific
 applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment
 used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other
 transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and
 devices related to power plant. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For
 details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR
 PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING
 WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT
 LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS
 ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION,
 INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF
 INFORMATION, OR NONINFRINGEMENT.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please
 use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without
 limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF
 NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

Toshiba Electronic Devices & Storage Corporation

https://toshiba.semicon-storage.com/

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LDO Voltage Regulators category:

Click to view products by Toshiba manufacturer:

Other Similar products are found below:

030014BB 1117CD-ADJ 2SB1260FRAT100R 404831RB 4A2D 6206A33 662K-JSM 702087BB 7805AS 78L05 78L05 78L05G
78L05L(30V) 78L05L(35V) 78L05(LX) 78L05S 78L05S 78L05S 78L05S 78L05S-150 78L05(SOT-89) 78L05(TO-92) 78L08L(30V) 78L09
78L10 78L10 78L12 78L12 78L12 78L12 78L12G 78L12L(35V) 78L15-150 78L33 78L33 78L33-150 78M05 78M05 78M05 78M05(LX)
78M09 78M12 78M12 79L05 79L06 79L12 79L12 82-512 A3RW-4.0/1/S/IP21 A4481KLJTR-T A8305SESTR-T